



ECE606: Solid State Devices
Lecture 19: Numerical Solution of Transport Equations

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Outline

- 1) Basic Transport Equations**
- 2) Gridding and finite differences
- 3) Discretizing equations and boundary conditions
- 4) Conclusion

REF. A primer on semiconductor device simulation
... M. Lundstrom (nanohub.org)

Equations to solve ... analytical/numerical approach

$$\nabla \cdot D = q(p - n + N_D^+ - N_A^-)$$

← Band-diagram

$$\frac{\partial n}{\partial t} = \frac{1}{q} \nabla \cdot \mathbf{J}_N - r_N + g_N$$

$$\mathbf{J}_N = qn\mu_N E + qD_N \nabla n$$

$$\frac{\partial p}{\partial t} = \frac{-1}{q} \nabla \cdot \mathbf{J}_P - r_P + g_P$$

← Diffusion approximation,
Minority carrier transport,
Ambipolar transport

$$\mathbf{J}_P = qp\mu_P E - qD_P \nabla p$$

1) The Semiconductor Equations

Conservation Laws:

$$\nabla \cdot \vec{D} = \rho$$

$$\nabla \cdot \left(\vec{J}_n / -q \right) = (g_N - r_N)$$

$$\nabla \cdot \left(\vec{J}_p / q \right) = (g_P - r_P)$$

(steady-state)

Constitutive Relations:

$$\vec{D} = \kappa \epsilon_0 \vec{E} = -\kappa \epsilon_0 \vec{\nabla} V$$

$$\rho = q(p - n + N_D^+ - N_A^-)$$

$$\vec{J}_n = nq\mu_n \vec{E} + qD_n \vec{\nabla} n$$

$$\vec{J}_p = pq\mu_p \vec{E} - qD_p \vec{\nabla} p$$

$$g_{N,P} = f(n, p) \text{ etc.}$$

1) The Mathematical Problem

The “Semiconductor Equations”

$$\nabla \cdot \vec{D} = \rho$$

$$\nabla \cdot \left(\vec{J}_n / -q \right) = (g_N - r_N)$$

$$\nabla \cdot \left(\vec{J}_p / q \right) = (g_N - r_N)$$

3 coupled, nonlinear,
second order PDE's
for the 3 unknowns:

$$V(\vec{r}) \quad n(\vec{r}) \quad p(\vec{r})$$

Conservations laws: **exact**
Transport eqs. (drift-diffusion): **approximate**

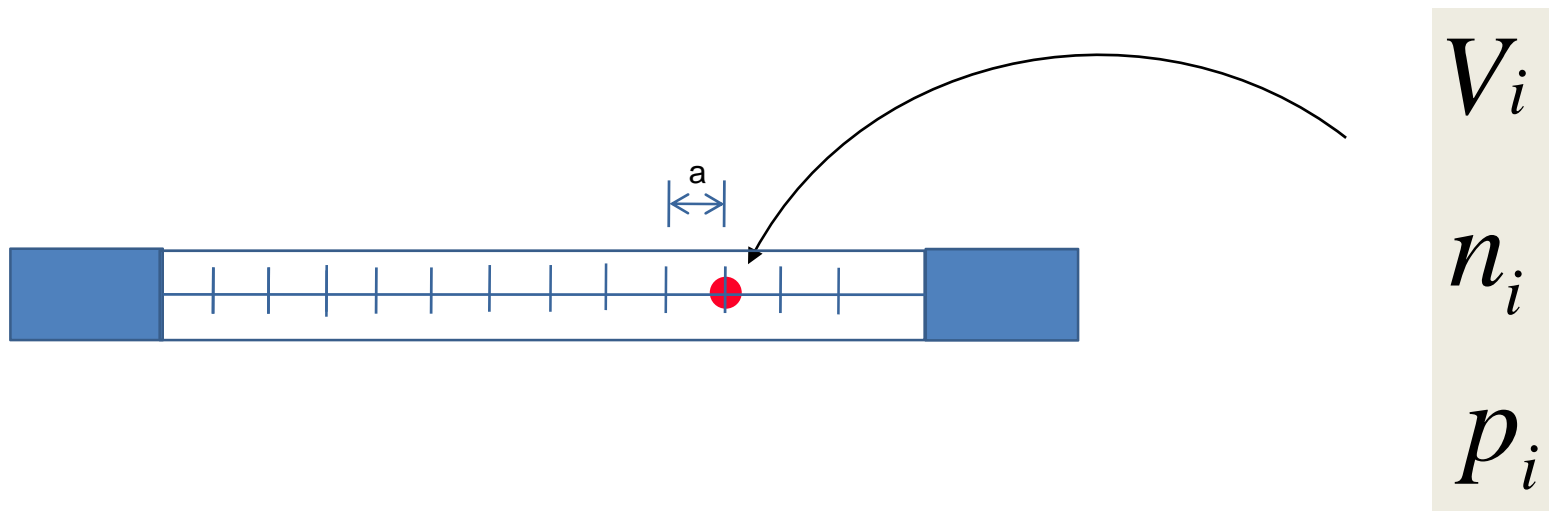
Outline

- 1) Basic Transport Equations
- 2) Gridding and finite differences**
- 3) Making up the matrix and boundary conditions
- 4) Conclusion

2) The Grid

(ii) “exact” numerical solutions

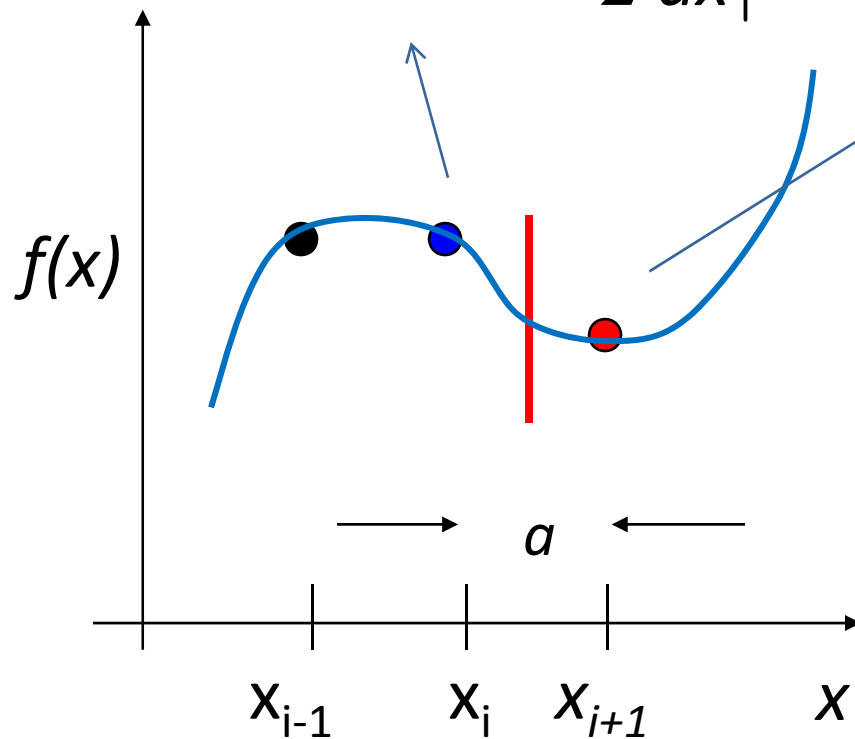
N nodes
3N unknowns



Finite Difference Expression for Derivative

$$f(x_0) = f(x_0 + a/2) - \frac{a}{2} \left. \frac{df}{dx} \right|_{x_0 + a/2}$$

$$f(x_0 + a) = f(x_0 + a/2) + \frac{a}{2} \left. \frac{df}{dx} \right|_{x_0 + a/2}$$



$$\left. \frac{df}{dx} \right|_{(x_{i+1/2})} = \frac{f_{i+1} - f_i}{a}$$

“centered difference”

The Second Derivative ...

$$f(x_0 + a) = f(x_0) + a \left. \frac{df}{dx} \right|_{x_0=a} + \frac{a^2}{2} \left. \frac{d^2 f}{dx^2} \right|_{x_0=a} + \dots$$

$$f(x_0 - a) = f(x_0) - a \left. \frac{df}{dx} \right|_{x_0=a} + \frac{a^2}{2} \left. \frac{d^2 f}{dx^2} \right|_{x_0=a} - \dots$$

$$f(x_0 + a) + f(x_0 - a) - 2f(x_0) = a^2 \left. \frac{d^2 f}{dx^2} \right|_{x_0=a}$$

$$\left. \frac{d^2 f}{dx^2} \right|_i = \frac{f_{i-1} - 2f_i + f_{i+1}}{a^2}$$

Outline

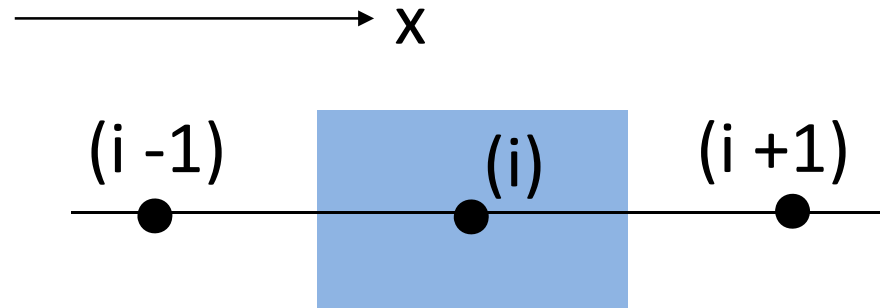
- 1) Basic Transport Equations
- 2) Gridding and finite differences
- 3) Discretizing equations and boundary conditions**
- 4) Conclusion

2) Control Volume

3 unknowns at each node:

$$V_i, n_i, p_i$$

Need 3 equations
at each node



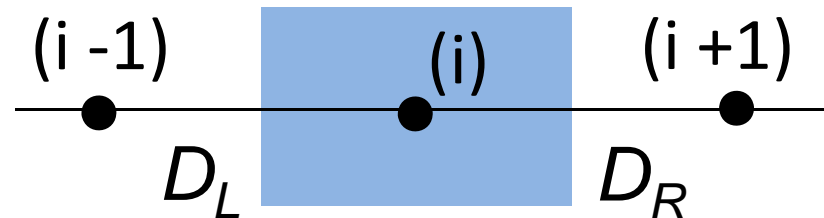
“control volume”

Discretizing Poisson's Equation

$$\nabla^2 V = -\rho / K_s \epsilon_0$$

$$\nabla \cdot \mathbf{D} = \rho \quad \mathbf{D} = K_s \epsilon_0 \mathbf{E} = -K_s \epsilon_0 \nabla V$$

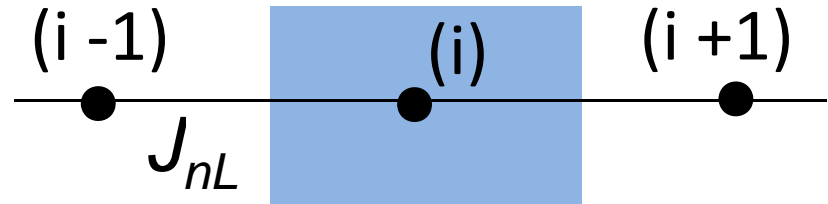
$$\frac{V_{(i-1)} - V_{(i)} + V_{(i+1)}}{a^2} = -\frac{q}{K_s \epsilon_0} (p_i - n_i + N_{D,i}^+ - N_{A,i}^-)$$



$$F_V^i(V_{i-1}, V_i, V_{i+1}, n_i, p_i) = 0$$

Discretizing Continuity Equations

$$\nabla \cdot \vec{J}_n = -q(g_N - r_N)$$



$$J_{nL} = -nq\mu_n \frac{dV}{dx} + kT\mu_n \frac{dn}{dx}$$

The simplest approach.....

$$\frac{J_{nL}}{kT\mu_n} = - \left(\frac{n_{i-1} + n_i}{2} \right) \left(\frac{V_i - V_{i-1}}{a(kT/q)} \right) + \left(\frac{n_i - n_{i-1}}{a} \right)$$

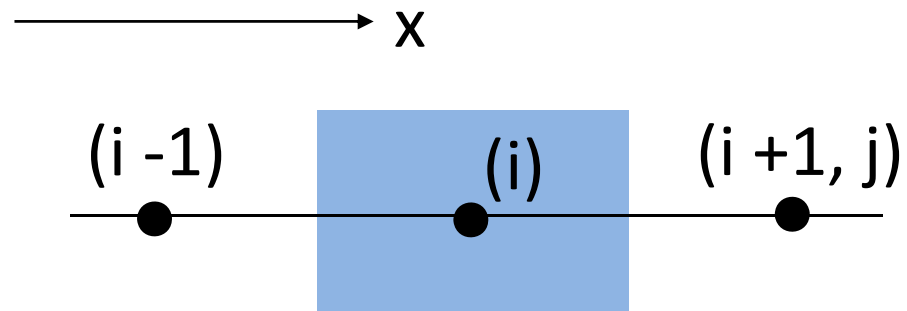
$$F_n^i(V_{i-1}, V_i, n_i, n_{i-1}, p_i, p_{i-1}) = 0$$

Three Discretized Equations

$$F_V^i = 0$$

$$F_n^i = 0$$

$$F_p^i = 0$$



3 unknowns at each node

N nodes

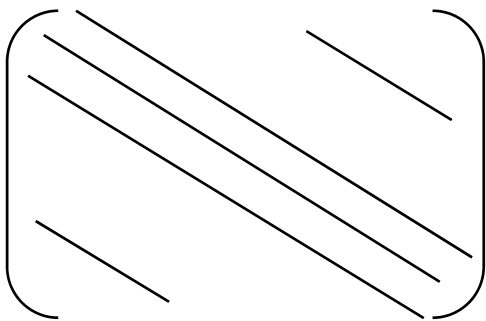
$3N$ unknowns and $3N$ equations (nonlinear!)

Numerical Solution – Poisson Equation Only

- Have a system of $3N$ nonlinear equations to solve
- Recall Poisson's equation at node (i):

$$F_V^i(V_{i-1}, V_i, V_{i+1}, n_i, p_i) = 0$$

linear if n_i and p_i are known $[A]\vec{V} = \vec{b}$

$[A]:$ 

$$\vec{V} = \begin{bmatrix} V_1 \\ V_2 \\ \vdots \\ V_N \end{bmatrix}$$

Boundary conditions

$$n_0 p_0 = n_i^2$$

$$n_{N+1} p_{N+1} = n_i^2$$

Dopant density

a

$$V = V_A$$

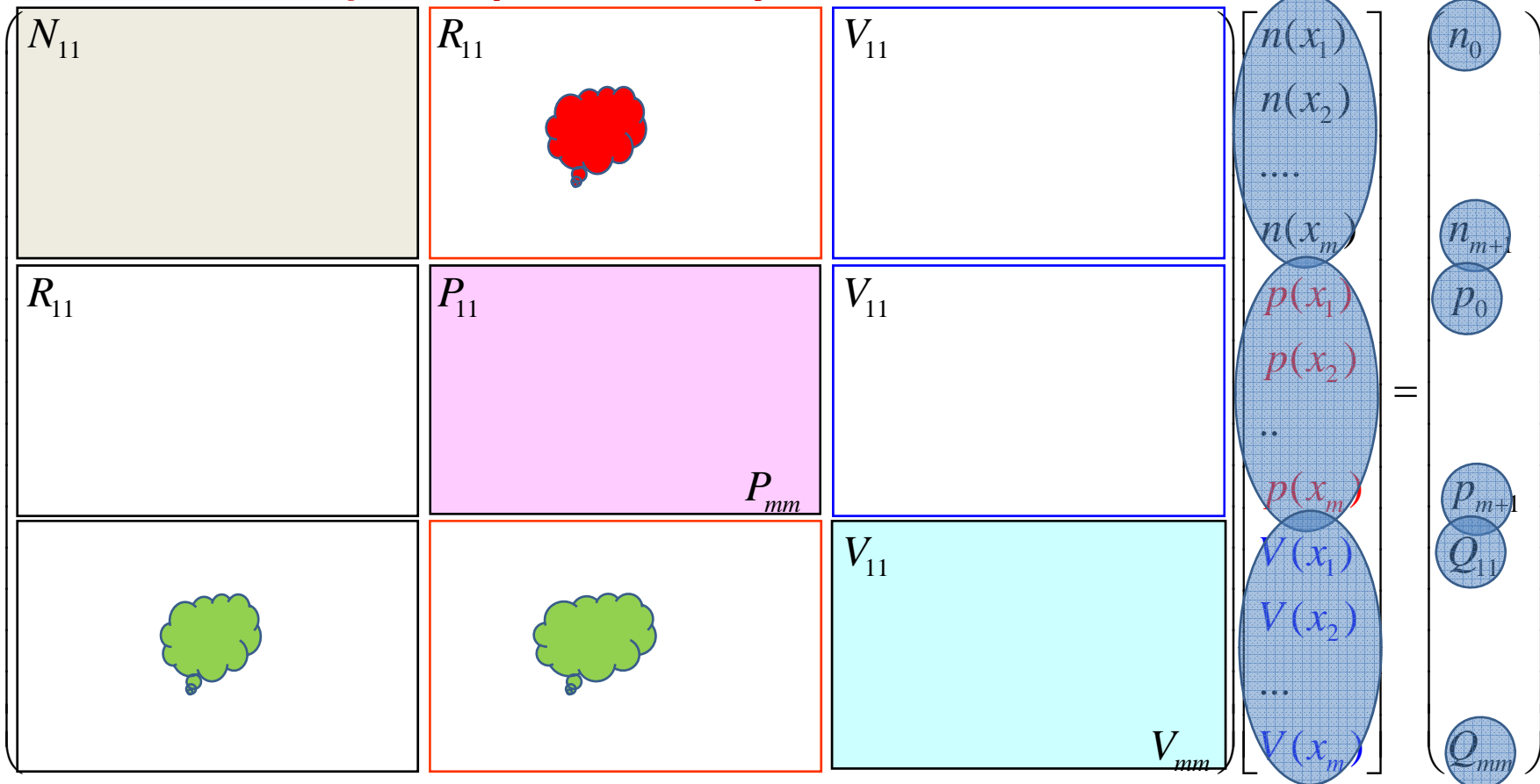
$$V = 0$$

Numerical Solution...

n-continuity

p-continuity

Poisson



3) Uncoupled Numerical Solution

The semiconductor equations are nonlinear!
(but they are linear individually)

Uncoupled solution procedure



repeat
until
satisfied

Guess V, n, p

Solve Poisson
for new V

Solve electron
cont for new n

Solve hole
cont for new p

Summary

- 1) Two methods to solve drift-diffusion equation consistently – analytical and numerical.
- 2) Analytical solution provides great insight and the solution methodology is similar to that of Schrodinger equations.
- 3) Numerical solution is more versatile. One begins with a set of equations and boundary conditions, discretize the equations on a grid with N nodes to obtain $3N$ nonlinear equations in $3N$ unknowns, and solve the system of nonlinear equations by iteration.